

808nm 200mw Single Mode Laser Diodes | Built-in PD

808nm~810nm SM LD with TO18 5.6mm Package | 200mW Output Power

WSLD-808-200m-1-PD

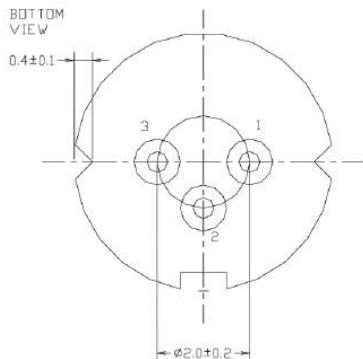
Wavespectrum Laser Group

www.wavespectrum-laser.com

808nm Laser Diode SM 200mw		Wavespectrum Laser Group	
Reverse Voltage	V_r	2.0	V
Operating Temperature	T_{op}	-10~+70	°C
Storage Temperature	T_{stg}	-40 ~ +80	°C
Lead soldering temperature (10 sec.)	T_{ls}	260	°C
Features:	<ul style="list-style-type: none"> • 808nm • TO18 Package • Single Mode Beam • Built-in PD 		
Applications:	<ul style="list-style-type: none"> • Medical laser treatment • Laser indicator • Others 		
Specifications	WSLD-808-200m-1-PD		
	Min	Type	Max
Center Wavelength@25°C	800nm	808nm	815nm
Spectral Width (FWHM)	1nm	1.5nm	2.5nm
Output Power	----	200mw	----
Emitter Size	----	3*1.5um	----
Beam Divergence (FWHM)	12° \perp x 6°//	16° \perp x 8°//	20° \perp x 10°//
Monitor Current	0.15mA	0.5mA	0.9mA
Slope Efficiency	0.8mW/mA	1.1mW/mA	1.3mW/mA
Threshold Current (Typ.)	----	50mA	70mA
Operating Current (Typ.)	----	230mA	260mA
Operating Voltage	----	2.0V	2.4V
Package Style	TO18		
Photodiodes	Optional		



TO18(5.6mm) Package View



1	LD(-)
2	LD (+) PD (-)
3	PD(+)

Electrically shorten LD module and store in non-extreme conditions.
Suggest using the constant current power supply.

